

# MMBT6427LT1G, SMMBT6427LT1G

## Darlington Transistor

### NPN Silicon

#### Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

| Rating                         | Symbol    | Value | Unit |
|--------------------------------|-----------|-------|------|
| Collector - Emitter Voltage    | $V_{CEO}$ | 40    | Vdc  |
| Collector - Base Voltage       | $V_{CBO}$ | 40    | Vdc  |
| Emitter - Base Voltage         | $V_{EBO}$ | 12    | Vdc  |
| Collector Current - Continuous | $I_C$     | 500   | mAdc |

#### THERMAL CHARACTERISTICS

| Characteristic  | Symbol          | Max         | Unit                       |
|---|-----------------|-------------|----------------------------|
| Total Device Dissipation FR-5 Board,<br>(Note 1) $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$        | $P_D$           | 225<br>1.8  | mW<br>mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction-to-Ambient   | $R_{\theta JA}$ | 556         | $^\circ\text{C}/\text{W}$  |
| Total Device Dissipation Alumina Substrate,<br>(Note 2) $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$           | 300<br>2.4  | mW<br>mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction-to-Ambient   | $R_{\theta JA}$ | 417         | $^\circ\text{C}/\text{W}$  |
| Junction and Storage Temperature  | $T_J, T_{stg}$  | -55 to +150 | $^\circ\text{C}$           |

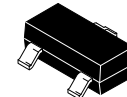
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.

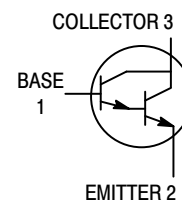


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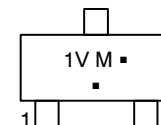
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SOT-23 (TO-236)  
CASE 318  
STYLE 6



#### MARKING DIAGRAM



1V = Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### ORDERING INFORMATION

| Device        | Package             | Shipping†         |
|---------------|---------------------|-------------------|
| MMBT6427LT1G  | SOT-23<br>(Pb-Free) | 3,000 Tape & Reel |
| SMMBT6427LT1G | SOT-23<br>(Pb-Free) | 3,000 Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic  | Symbol              | Min                        | Max                           | Unit            |
|---|---------------------|----------------------------|-------------------------------|-----------------|
| <b>OFF CHARACTERISTICS</b>  |                     |                            |                               |                 |
| Collector – Emitter Breakdown Voltage<br>( $I_C = 10\text{ mAdc}$ , $V_{BE} = 0$ )  | $V_{(BR)CEO}$       | 40                         | –                             | Vdc             |
| Collector – Base Breakdown Voltage<br>( $I_C = 100\ \mu\text{Adc}$ , $I_E = 0$ )  | $V_{(BR)CBO}$       | 40                         | –                             | Vdc             |
| Emitter – Base Breakdown Voltage<br>( $I_C = 10\ \mu\text{Adc}$ , $I_C = 0$ )   | $V_{(BR)EBO}$       | 12                         | –                             | Vdc             |
| Collector Cutoff Current<br>( $V_{CE} = 25\text{ Vdc}$ , $I_B = 0$ )  | $I_{CES}$           | –                          | 1.0                           | $\mu\text{Adc}$ |
| Collector Cutoff Current<br>( $V_{CB} = 30\text{ Vdc}$ , $I_E = 0$ )  | $I_{CBO}$           | –                          | 50                            | nAdc            |
| Emitter Cutoff Current<br>( $V_{EB} = 10\text{ Vdc}$ , $I_C = 0$ )  | $I_{EBO}$           | –                          | 50                            | nAdc            |
| <b>ON CHARACTERISTICS</b>   |                     |                            |                               |                 |
| DC Current Gain<br>( $I_C = 10\text{ mAdc}$ , $V_{CE} = 5.0\text{ Vdc}$ )<br>( $I_C = 100\text{ mAdc}$ , $V_{CE} = 5.0\text{ Vdc}$ )<br>( $I_C = 500\text{ mAdc}$ , $V_{CE} = 5.0\text{ Vdc}$ ) | $h_{FE}$            | 10,000<br>20,000<br>14,000 | 100,000<br>200,000<br>140,000 | –               |
| Collector – Emitter Saturation Voltage<br>( $I_C = 50\text{ mAdc}$ , $I_B = 0.5\text{ mAdc}$ )<br>( $I_C = 500\text{ mAdc}$ , $I_B = 0.5\text{ mAdc}$ )   | $V_{CE(sat)}^{(3)}$ | –<br>–                     | 1.2<br>1.5                    | Vdc             |
| Base – Emitter Saturation Voltage<br>( $I_C = 500\text{ mAdc}$ , $I_B = 0.5\text{ mAdc}$ )  | $V_{BE(sat)}$       | –                          | 2.0                           | Vdc             |
| Base – Emitter On Voltage<br>( $I_C = 50\text{ mAdc}$ , $V_{CE} = 5.0\text{ Vdc}$ )   | $V_{BE(on)}$        | –                          | 1.75                          | Vdc             |
| <b>SMALL-SIGNAL CHARACTERISTICS</b>   |                     |                            |                               |                 |
| Output Capacitance<br>( $V_{CB} = 10\text{ Vdc}$ , $I_E = 0$ , $f = 1.0\text{ MHz}$ )   | $C_{obo}$           | –                          | 7.0                           | pF              |
| Input Capacitance<br>( $V_{EB} = 0.5\text{ Vdc}$ , $I_C = 0$ , $f = 1.0\text{ MHz}$ )   | $C_{ibo}$           | –                          | 15                            | pF              |
| Current Gain – High Frequency<br>( $I_C = 10\text{ mAdc}$ , $V_{CE} = 5.0\text{ Vdc}$ , $f = 100\text{ MHz}$ )  | $ h_{fe} $          | 1.3                        | –                             | Vdc             |
| Noise Figure<br>( $I_C = 1.0\text{ mAdc}$ , $V_{CE} = 5.0\text{ Vdc}$ , $R_S = 100\text{ k}\Omega$ , $f = 1.0\text{ kHz}$ )   | NF                  | –                          | 10                            | dB              |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle = 2.0%.

# MMBT6427LT1G, SMMBT6427LT1G

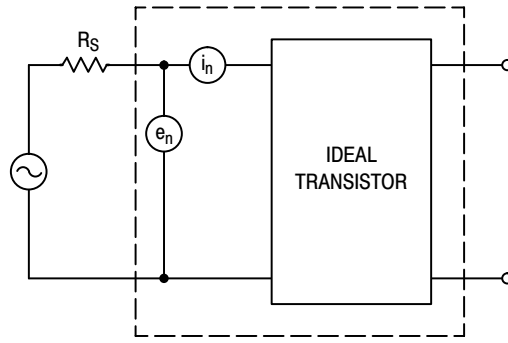


Figure 1. Transistor Noise Model

## NOISE CHARACTERISTICS

( $V_{CE} = 5.0 \text{ Vdc}$ ,  $T_A = 25^\circ\text{C}$ )

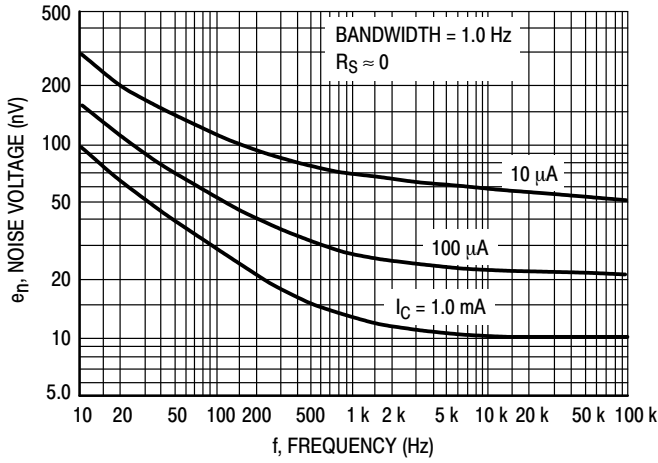


Figure 2. Noise Voltage

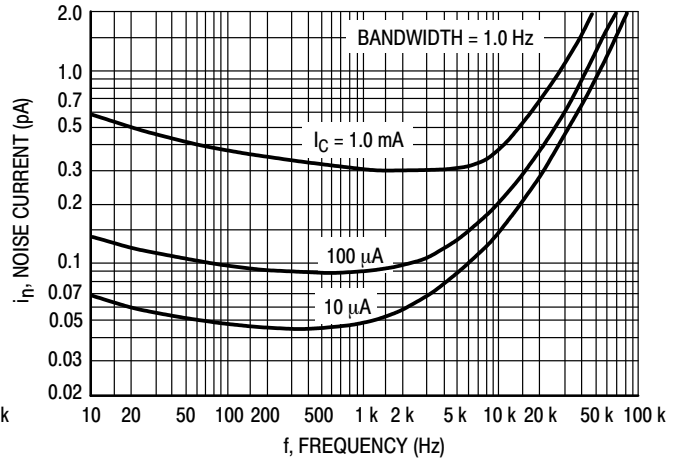


Figure 3. Noise Current

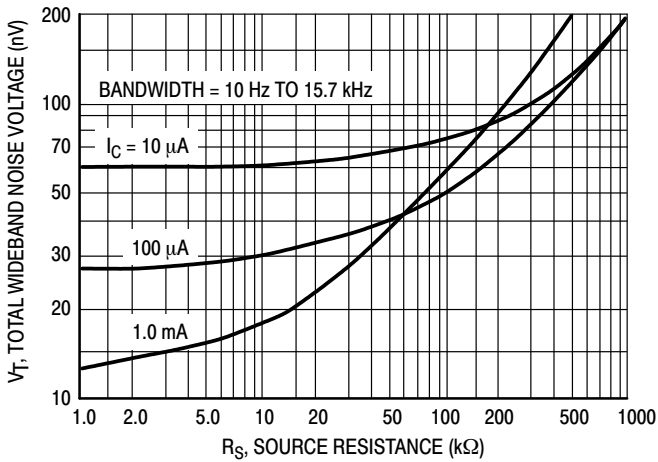


Figure 4. Total Wideband Noise Voltage

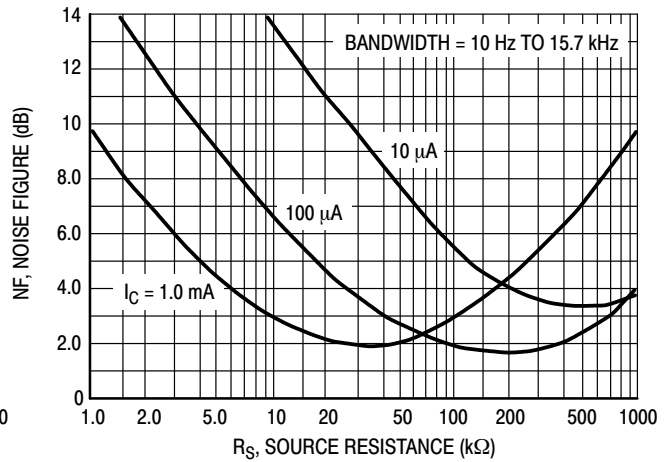


Figure 5. Wideband Noise Figure

# MMBT6427LT1G, SMMBT6427LT1G

## SMALL-SIGNAL CHARACTERISTICS

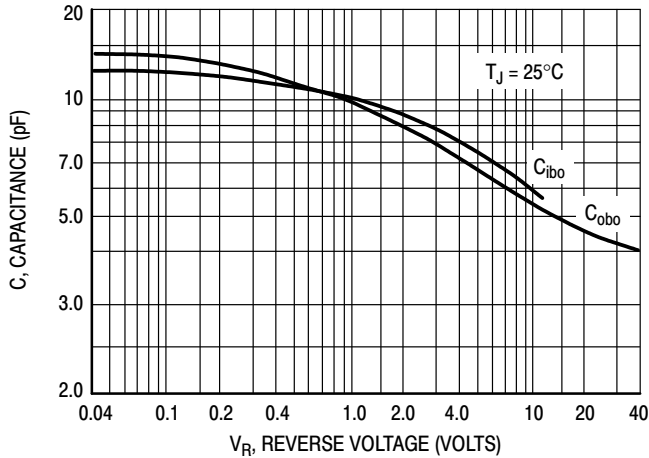


Figure 6. Capacitance

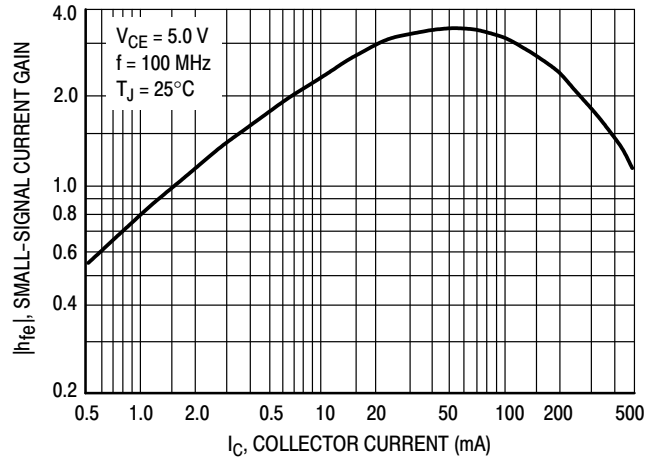


Figure 7. High Frequency Current Gain

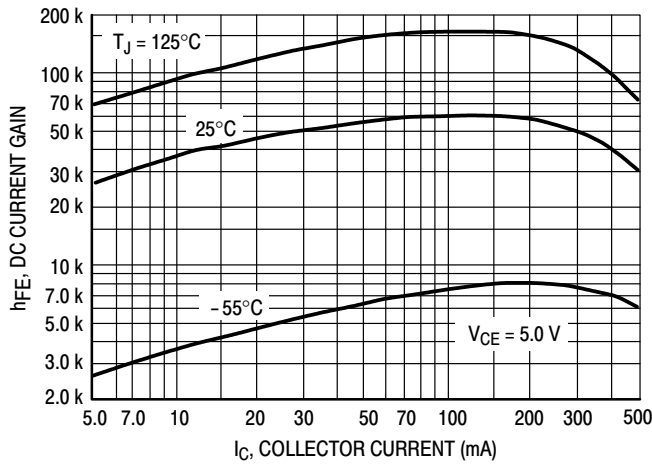


Figure 8. DC Current Gain

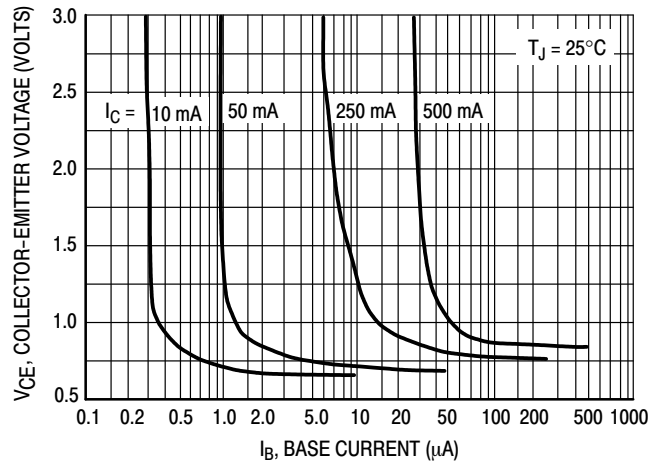


Figure 9. Collector Saturation Region

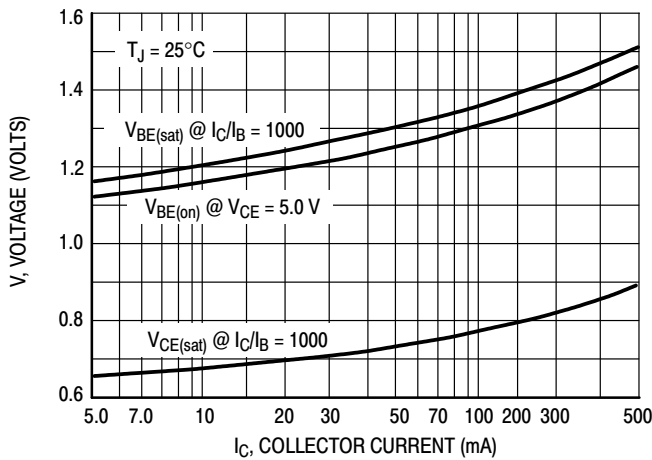


Figure 10. "On" Voltages

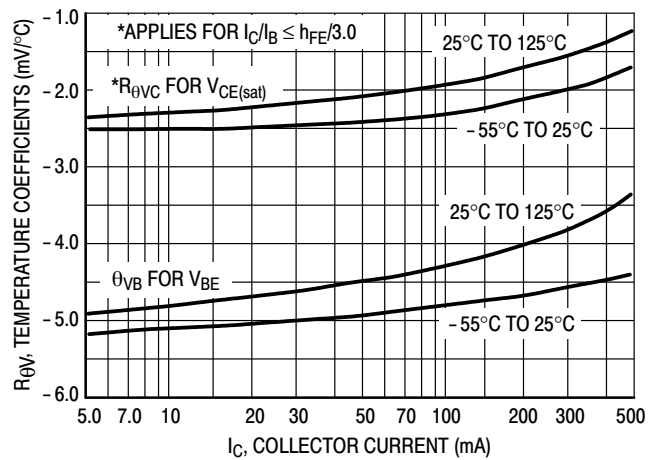


Figure 11. Temperature Coefficients

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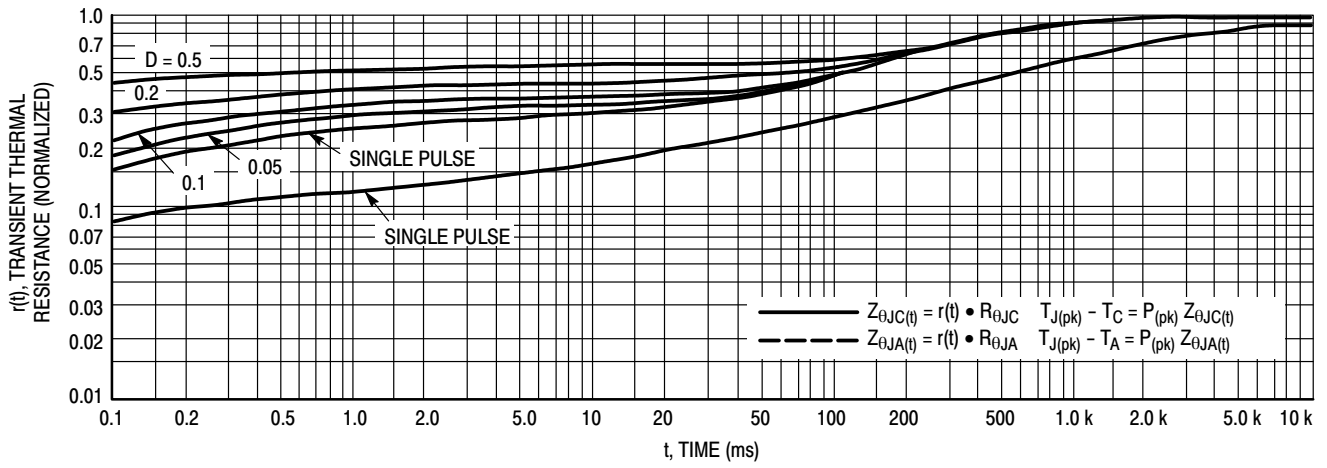
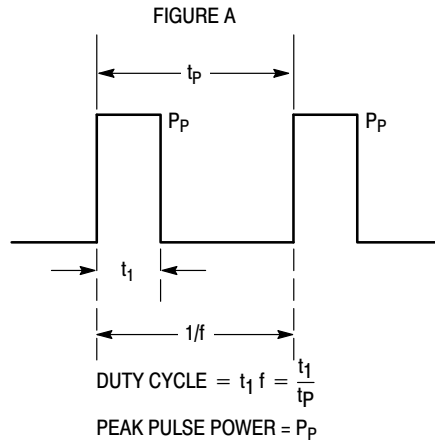


Figure 12. Thermal Response

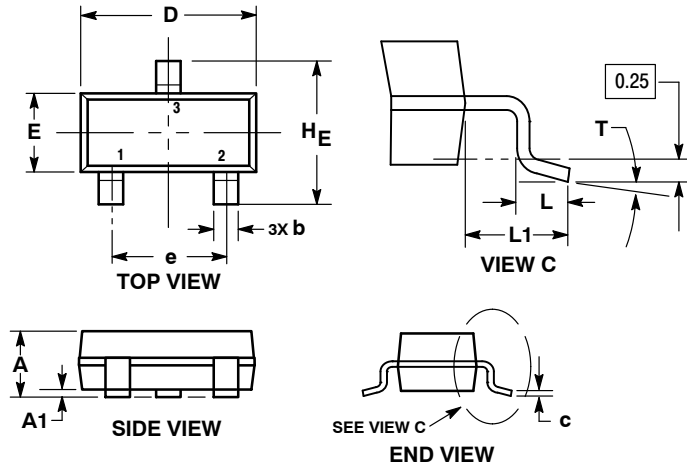


**Design Note: Use of Transient Thermal Resistance Data**

# MMBT6427LT1G, SMMBT6427LT1G

## PACKAGE DIMENSIONS

SOT-23 (TO-236)  
CASE 318-08  
ISSUE AR



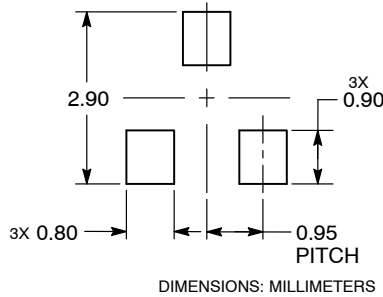
### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | MILLIMETERS |      |      | INCHES |       |       |
|-----|-------------|------|------|--------|-------|-------|
|     | MIN         | NOM  | MAX  | MIN    | NOM   | MAX   |
| A   | 0.89        | 1.00 | 1.11 | 0.035  | 0.039 | 0.044 |
| A1  | 0.01        | 0.06 | 0.10 | 0.000  | 0.002 | 0.004 |
| b   | 0.37        | 0.44 | 0.50 | 0.015  | 0.017 | 0.020 |
| c   | 0.08        | 0.14 | 0.20 | 0.003  | 0.006 | 0.008 |
| D   | 2.80        | 2.90 | 3.04 | 0.110  | 0.114 | 0.120 |
| E   | 1.20        | 1.30 | 1.40 | 0.047  | 0.051 | 0.055 |
| e   | 1.78        | 1.90 | 2.04 | 0.070  | 0.075 | 0.080 |
| L   | 0.30        | 0.43 | 0.55 | 0.012  | 0.017 | 0.022 |
| L1  | 0.35        | 0.54 | 0.69 | 0.014  | 0.021 | 0.027 |
| HE  | 2.10        | 2.40 | 2.64 | 0.083  | 0.094 | 0.104 |
| T   | 0°          | ---  | 10°  | 0°     | ---   | 10°   |

STYLE 6:  
PIN 1. BASE  
2. EMITTER  
3. COLLECTOR

### RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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